**SGM8252A** 



# 2.8MHz, High Voltage, High Precision, Low Noise **Rail-to-Rail Output Operational Amplifier**

#### GENERAL DESCRIPTION

The dual SGM8252A is a rail-to-rail output, low noise and high precision operational amplifier which has low input offset voltage and bias current. It is guaranteed to operate from 4.5V to 36V single supply.

The rail-to-rail output swing provided by the SGM8252A makes both high-side and low-side sensing easy. The combination of these characteristics makes the SGM8252A good choice for temperature, position and pressure sensors, medical equipment and strain gauge amplifiers, or any other 4.5V to 36V application requiring precision and long term stability.

The dual SGM8252A is available in Green SOIC-8 and MSOP-8 packages. It is rated over the -40°C to +125°C temperature range.

#### **FEATURES**

Low Offset Voltage: 5µV (TYP)

Rail-to-Rail Output Swing

• 4.5V to 36V Single Supply Operation Open-Loop Voltage Gain: 150dB (TYP)

• PSRR: 150dB (TYP) • CMRR: 135dB (TYP)

• 0.1Hz to 10Hz Noise: 0.4μV<sub>P.P</sub>

Input Voltage Noise Density: 20nV/√Hz at 1kHz

• Gain-Bandwidth Product: 2.8MHz

Low Supply Current: 460μA/Amplifier (TYP)

• Overload Recovery Time: 3µs

-40°C to +125°C Operating Temperature Range

Available in Green SOIC-8 and MSOP-8 Packages

#### **APPLICATIONS**

Temperature Measurements Pressure Sensors Precision Current Sensing Electronic Scales Strain Gauge Amplifiers Medical Instrumentation Thermocouple Amplifiers Handheld Test Equipment



#### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8252A	SOIC-8	-40°C to +125°C	SGM8252AXS8G/TR	SGM 8252AXS8 XXXXX	Tape and Reel, 4000
SGIVIO232A	MSOP-8	-40°C to +125°C	SGM8252AXMS8G/TR	SGM8252A XMS8 XXXXX	Tape and Reel, 4000

NOTE: XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

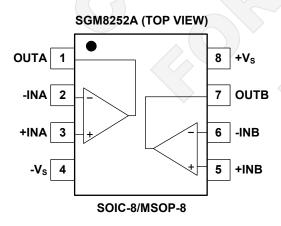
#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage	40V
Input Voltage Range (-V <sub>S</sub> ) - 0.3	$V \text{ to } (+V_S) + 0.3V$
Differential Input Voltage Range	15V to +15V
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	6000V
MM	300V
CDM	1000V

#### RECOMMENDED OPERATING CONDITIONS

Input Voltage Range	4.5V to 36V
Operating Temperature Range	

#### PIN CONFIGURATIONS



#### **OVERSTRESS CAUTION**

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

## **ELECTRICAL CHARACTERISTICS**

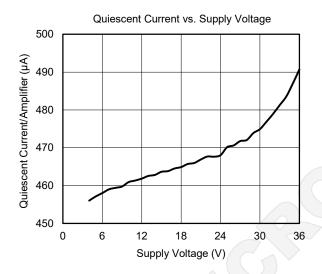
(At  $T_A$  = +25°C,  $V_S$  = ±2.5V to  $V_S$  = ±18V,  $V_{CM}$  = 0V and  $R_L$  = 10k $\Omega$  connected to 0V, Full = -40°C to +125°C, unless otherwise noted.)

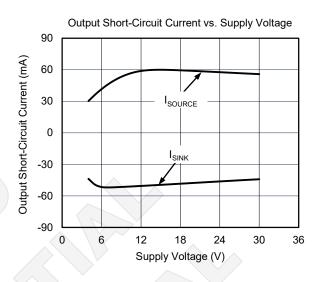
PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
INPUT CHARACTERISTICS							
Input Offset Voltage (Vos)		+25°C		5		μV	
Input Offset Voltage Drift ( $\Delta V_{OS}/\Delta T$ )		Full		20		nV/°C	
Input Bias Current (I <sub>B</sub> )		+25°C		±100		pА	
Input Offset Current (I <sub>OS</sub> )		+25°C		±200		pА	
Input Common Mode Voltage Range (V <sub>CM</sub> )		Full	(-V <sub>S</sub> ) - 0.05		(+V <sub>S</sub> ) -1.5	V	
Common Mode Rejection Ratio (1) (CMRR)	$V_{CM} = (-V_S) - 0.05V$ to $(+V_S) - 1.5V$	+25°C		135		dB	
On an Lagar Vallage Opin (A.)	$V_S = \pm 2.5 V, V_{OUT} = \pm 2.0 V$	+25°C		140		-ID	
Open-Loop Voltage Gain (A <sub>OL</sub> )	$V_S = \pm 18V, V_{OUT} = \pm 17.5V$	+25°C		150		dB	
OUTPUT CHARACTERISTICS							
Contract Voltage Contract from Pail	V <sub>S</sub> = ±2.5V	+25°C		13		.,	
Output Voltage Swing from Rail	V <sub>S</sub> = ±18V	+25°C		95		mV	
	V <sub>S</sub> = ±2.5V	+25°C		±32			
Output Short-Circuit Current (I <sub>SC</sub> )	V <sub>s</sub> = ±18V	+25℃		±48		mA	
POWER SUPPLY					•	•	
Operating Voltage Range (Vs)		Full	4.5		36	V	
Quiescent Current/Amplifier (I <sub>Q</sub> )	I <sub>OUT</sub> = 0	+25°C		460		μΑ	
Power Supply Rejection Ratio (1) (PSRR)	V <sub>s</sub> = 4.5V to 36V	+25℃		150		dB	
DYNAMIC PERFORMANCE				7			
Gain-Bandwidth Product (GBP)	V <sub>OUT</sub> = 100mV <sub>P-P</sub> , C <sub>L</sub> = 10pF	+25°C		2.8		MHz	
Slew Rate (SR)		+25°C		1.2		V/µs	
Settling Time to 0.1% (t <sub>s</sub> )	V <sub>IN</sub> = 1V Step, A <sub>V</sub> = +1	+25°C		0.8		μs	
Overload Recovery Time	$V_{IN} \times A_V > V_S$	+25°C		3		μs	
Total Harmonic Distortion + Noise (THD+N)	$V_{IN} = 2V_{P-P}, A_V = +1, f = 1kHz$	+25°C		0.0005		%	
NOISE							
Input Voltage Noise	f = 0.1Hz to 10Hz	+25℃		0.4		μV <sub>P-P</sub>	
	f = 0.1kHz	+25°C		20			
Input Voltage Noise Density (en)	f = 1kHz	+25°C		20		nV/√Hz	
	f = 10kHz	+25℃		23		]	

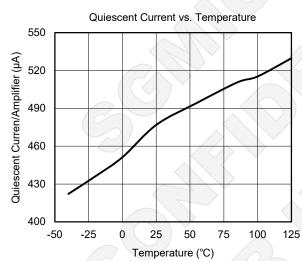
NOTE: 1. PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

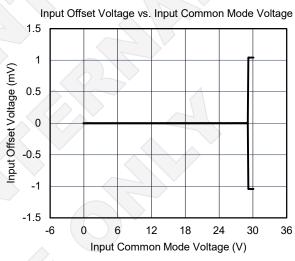
## TYPICAL PERFORMANCE CHARACTERISTICS

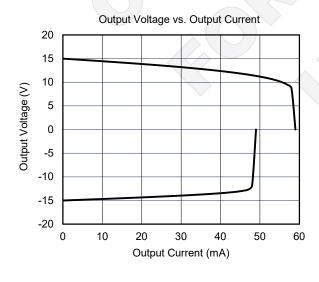
At  $T_A$  = +25°C,  $V_S$  = ±15V,  $C_L$  = 10pF and  $R_L$  = 10k $\Omega$ , unless otherwise noted.

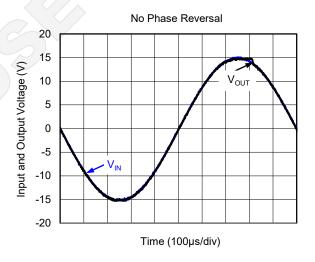






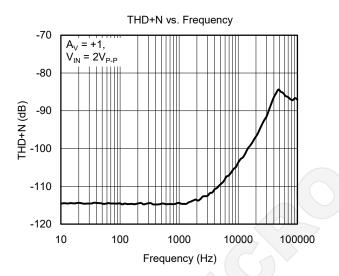


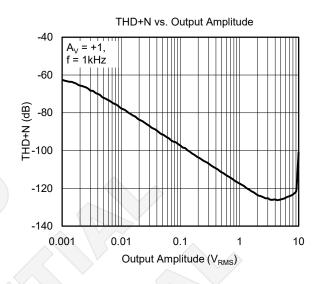


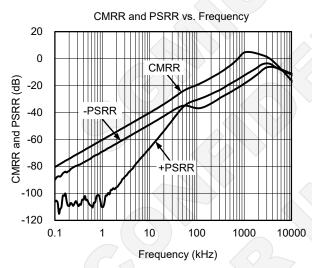


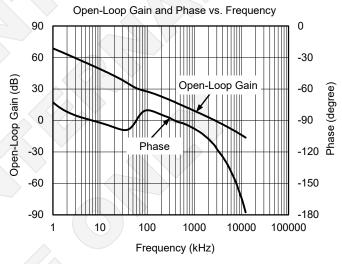
# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

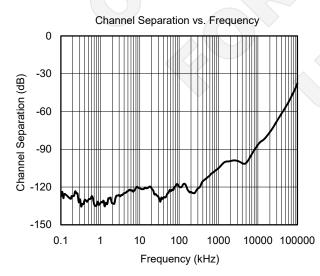
At  $T_A$  = +25°C,  $V_S$  = ±15V,  $C_L$  = 10pF and  $R_L$  = 10k $\Omega$ , unless otherwise noted.

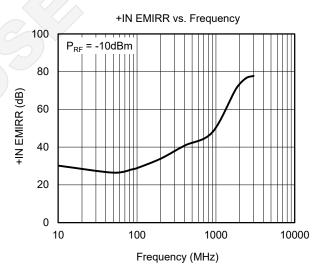






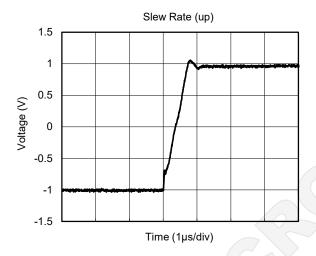


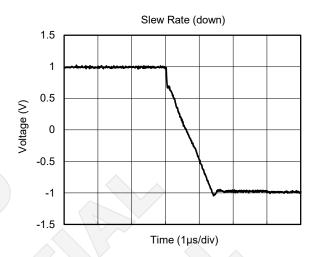


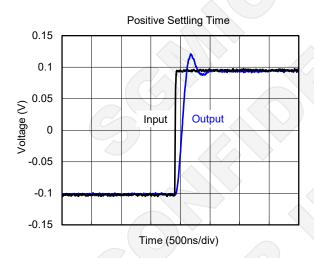


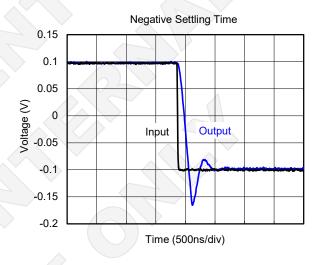
# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

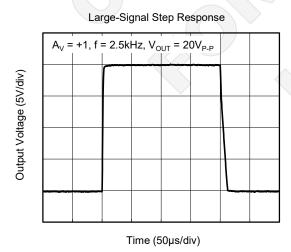
At T<sub>A</sub> = +25°C, V<sub>S</sub> = ±15V, C<sub>L</sub> = 10pF and R<sub>L</sub> = 10k $\Omega$ , unless otherwise noted.

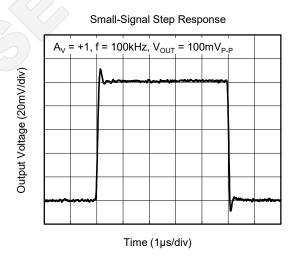






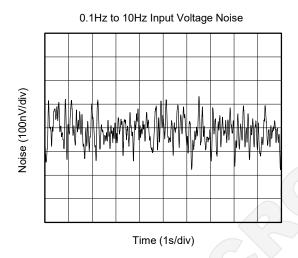


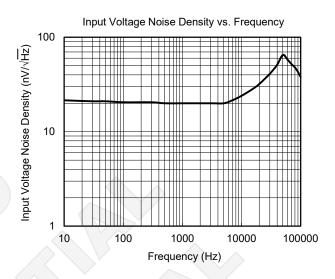


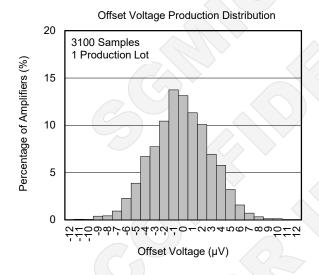


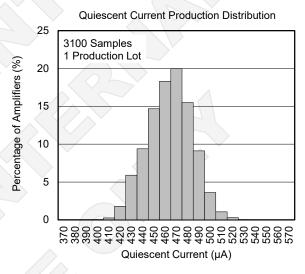
# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

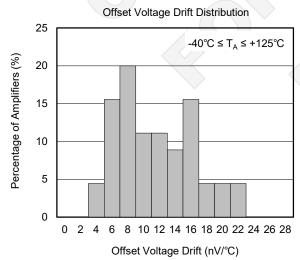
At  $T_A$  = +25°C,  $V_S$  = ±15V,  $C_L$  = 10pF and  $R_L$  = 10k $\Omega$ , unless otherwise noted.











### **APPLICATION NOTES**

#### **Driving Capacitive Loads**

The unity-gain follower (buffer) is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers and this results in ringing or even oscillation. Applications that require greater capacitive driving capability should use an isolation resistor between the output and the capacitive load like the circuit in Figure 1. The isolation resistor  $R_{\rm ISO}$  and the load capacitor  $C_{\rm L}$  form a zero to increase stability. The bigger the  $R_{\rm ISO}$  resistor value, the more stable  $V_{\rm OUT}$  will be. Note that this method results in a loss of gain accuracy because  $R_{\rm ISO}$  forms a voltage divider with the  $R_{\rm LOAD}$ .

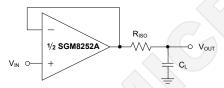


Figure 1. Indirectly Driving Heavy Capacitive Load

An improved circuit is shown in Figure 2. It provides DC accuracy as well as AC stability.  $R_{\text{F}}$  provides the DC accuracy by connecting the inverting input with the output.  $C_{\text{F}}$  and  $R_{\text{ISO}}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

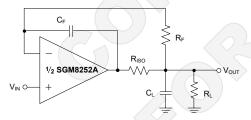


Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy

For non-buffer configuration, there are two other ways to increase the phase margin: (a) by increasing the amplifier's closed-loop gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node.

#### **Power-Supply Bypassing and Layout**

The SGM8252A operates from either a single 4.5V to 36V supply or dual  $\pm 2.25$ V to  $\pm 18$ V supplies. For

single-supply operation, bypass the power supply  $+V_S$  with a  $0.1\mu F$  ceramic capacitor which should be placed close to the  $+V_S$  pin. For dual-supply operation, both the  $+V_S$  and the  $+V_S$  supplies should be bypassed to ground with separate  $0.1\mu F$  ceramic capacitors.  $2.2\mu F$  tantalum capacitor can be added for better performance.

Good PC board layout techniques optimize performance by decreasing the amount of stray capacitance at the op amp's inputs and output. To decrease stray capacitance, minimize trace lengths and widths by placing external components as close to the device as possible. Use surface-mount components whenever possible.

For the operational amplifier, soldering the part to the board directly is strongly recommended. Try to keep the high frequency current loop area small to minimize the EMI (electromagnetic interference).

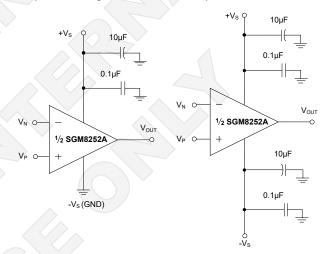


Figure 3. Amplifier with Bypass Capacitors

#### Grounding

A ground plane layer is important for SGM8252A circuit design. The length of the current path in an inductive ground return will create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance.

#### **Input-to-Output Coupling**

To minimize capacitive coupling, the input and output signal traces should not be in parallel. This helps reduce unwanted positive feedback.

#### TYPICAL APPLICATION CIRCUITS

#### **Differential Amplifier**

The circuit shown in Figure 4 performs the difference function. If the resistor ratios are equal  $(R_4/R_3 = R_2/R_1)$ , then  $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$ .

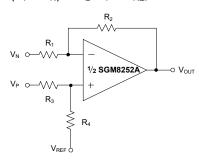


Figure 4. Differential Amplifier

#### **Instrumentation Amplifier**

The circuit in Figure 5 performs the same function as that in Figure 4 but with a high input impedance.

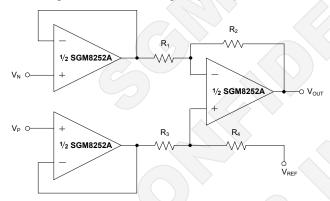


Figure 5. Instrumentation Amplifier

#### **Active Low-Pass Filter**

The low-pass filter shown in Figure 6 has a DC gain of  $(-R_2/R_1)$  and the -3dB corner frequency is  $1/2\pi R_2 C$ . Make sure the filter bandwidth is within the bandwidth of the amplifier. Feedback resistors with large values can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistor values as low as possible and consistent with output loading consideration.

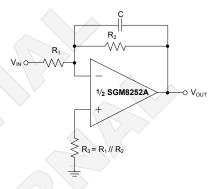
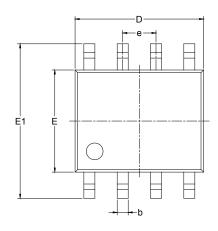
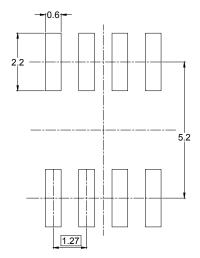


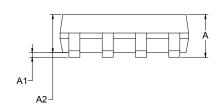
Figure 6. Active Low-Pass Filter

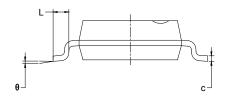
# PACKAGE OUTLINE DIMENSIONS SOIC-8





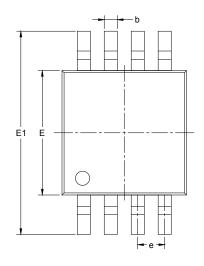
RECOMMENDED LAND PATTERN (Unit: mm)

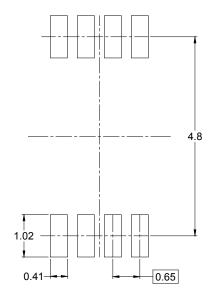




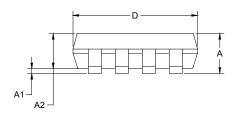
Symbol		nsions meters	Dimensions In Inches		
,	MIN	MIN MAX		MAX	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

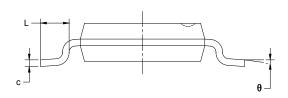
# PACKAGE OUTLINE DIMENSIONS MSOP-8





RECOMMENDED LAND PATTERN (Unit: mm)

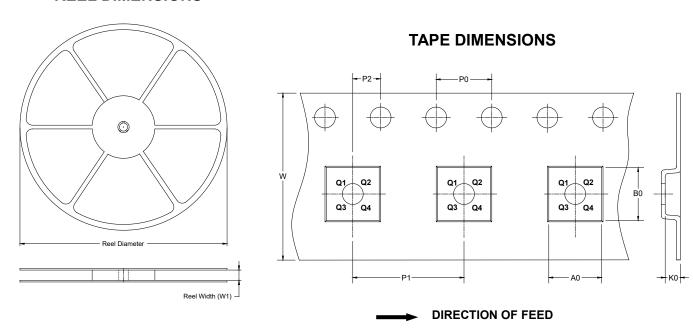




Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
Α	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
С	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
Е	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
е	0.650 BSC		0.026	BSC	
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	

# TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

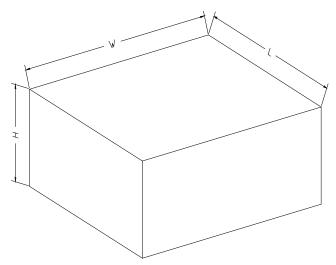


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5